

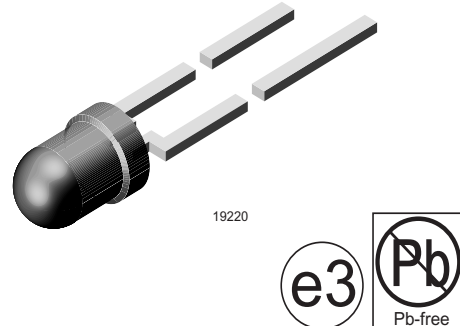
## High Intensity LED, $\varnothing$ 3 mm Tinted Diffused

### Description

This LED contains the double heterojunction (DH) GaAlAs on GaAs technology.

This deep red LED can be utilized over a wide range of drive current. It can be DC or pulse driven to achieve desired light output.

The device is available in a 3 mm tinted diffused package.



### Features

- Exceptional brightness
- Very high intensity even at low drive currents
- Wide viewing angle
- Low forward voltage
- 3 mm (T-1) tinted diffused package
- Deep red color
- Categorized for luminous intensity
- Outstanding material efficiency
- Lead-free device

### Applications

Bright ambient lighting conditions  
 Battery powered equipment  
 Indoor and outdoor information displays  
 Portable equipment  
 Telecommunication indicators  
 General use

### Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ( $\pm\phi$ )	Technology
TLDR4400	Red, $I_V > 25$ mcd	40 °	GaAlAs on GaAs
TLDR4401	Red, $I_V = (25$ to 50) mcd	40 °	GaAlAs on GaAs

### Absolute Maximum Ratings

$T_{amb} = 25$  °C, unless otherwise specified

#### TLDR440.

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC Forward current	$T_{amb} \leq 60$ °C	$I_F$	50	mA
Surge forward current	$t_p \leq 10$ $\mu$ s	$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 60$ °C	$P_V$	100	mW
Junction temperature		$T_j$	100	°C
Operating temperature range		$T_{amb}$	- 40 to + 100	°C
Storage temperature range		$T_{stg}$	- 55 to + 100	°C
Soldering temperature	$t \leq 5$ s, 2 mm from body	$T_{sd}$	260	°C
Thermal resistance junction/ambient		$R_{thJA}$	400	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

#### Red

#### TLDR440.

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 20\text{ mA}$	TLDR4400	$I_V$	25	45		mcd
		TLDR4401	$I_V$	25		50	mcd
Luminous intensity	$I_F = 1\text{ mA}$		$I_V$		2		mcd
Dominant wavelength	$I_F = 20\text{ mA}$		$\lambda_d$		648		nm
Peak wavelength	$I_F = 20\text{ mA}$		$\lambda_p$		650		nm
Spectral line half width	$I_F = 20\text{ mA}$		$\Delta\lambda$		20		nm
Angle of half intensity	$I_F = 20\text{ mA}$		$\phi$		$\pm 40$		deg
Forward voltage	$I_F = 20\text{ mA}$		$V_F$		1.8	2.2	V
Reverse current	$V_R = 6\text{ V}$		$I_R$			10	$\mu\text{A}$
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$		$C_j$		30		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

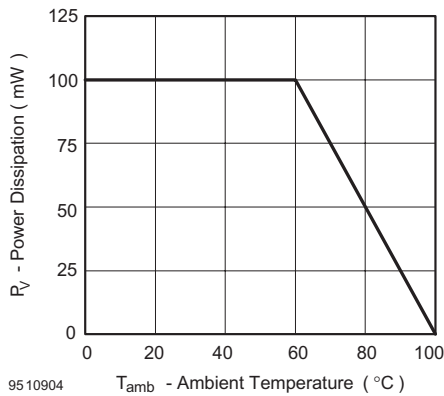


Figure 1. Power Dissipation vs. Ambient Temperature

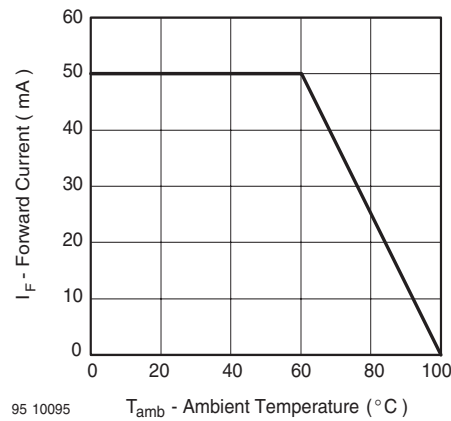


Figure 2. Forward Current vs. Ambient Temperature for InGaN

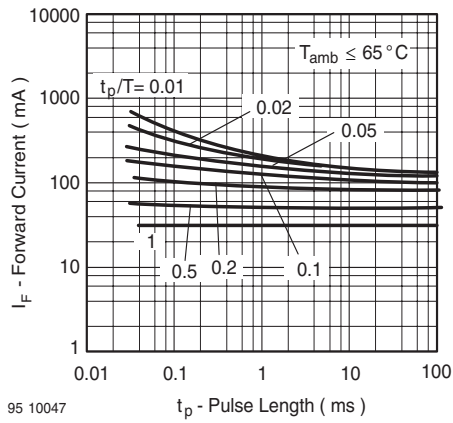


Figure 3. Forward Current vs. Pulse Length

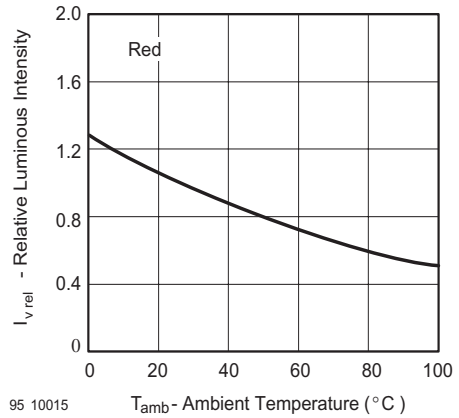


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

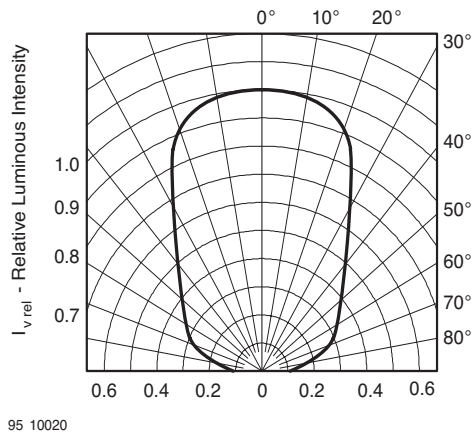


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

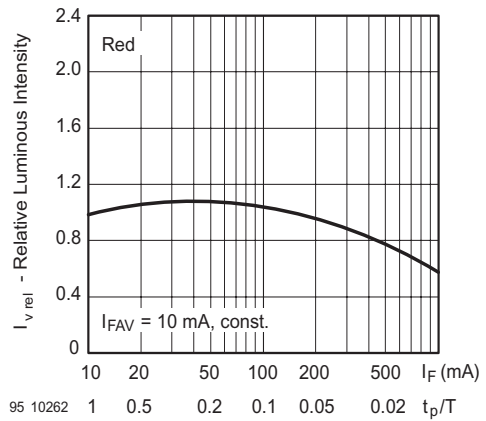


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

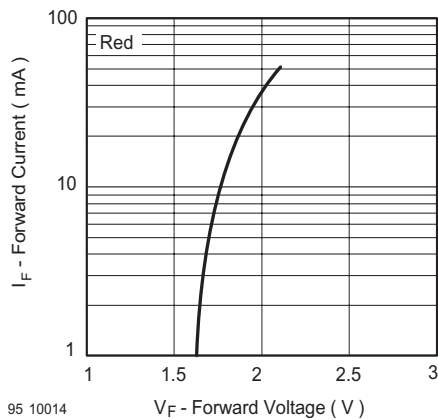


Figure 5.

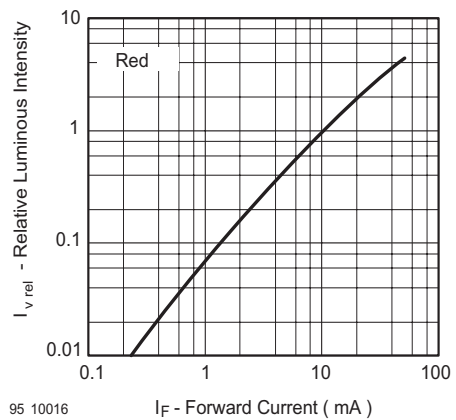


Figure 8. Relative Luminous Intensity vs. Forward Current

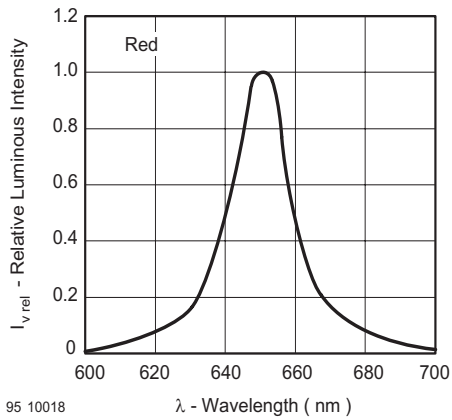
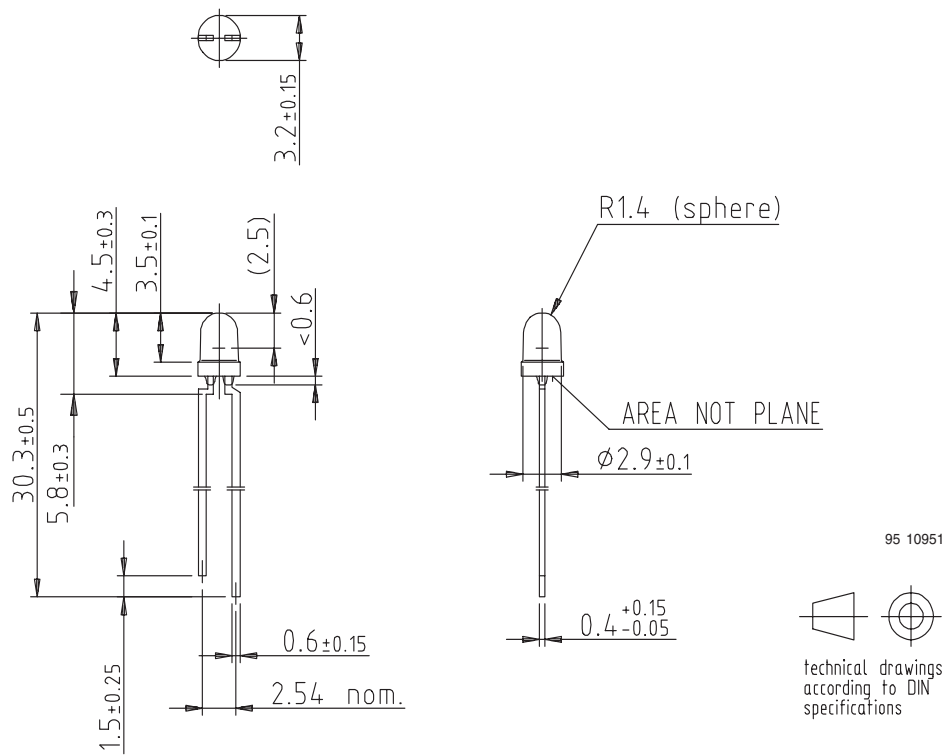


Figure 9. Relative Intensity vs. Wavelength

## Package Dimensions in mm





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2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

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The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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